

1 310 nm InGaAsP MQW-FP LASER DIODE
COAXIAL MODULE FOR OTDR APPLICATION

DESCRIPTION

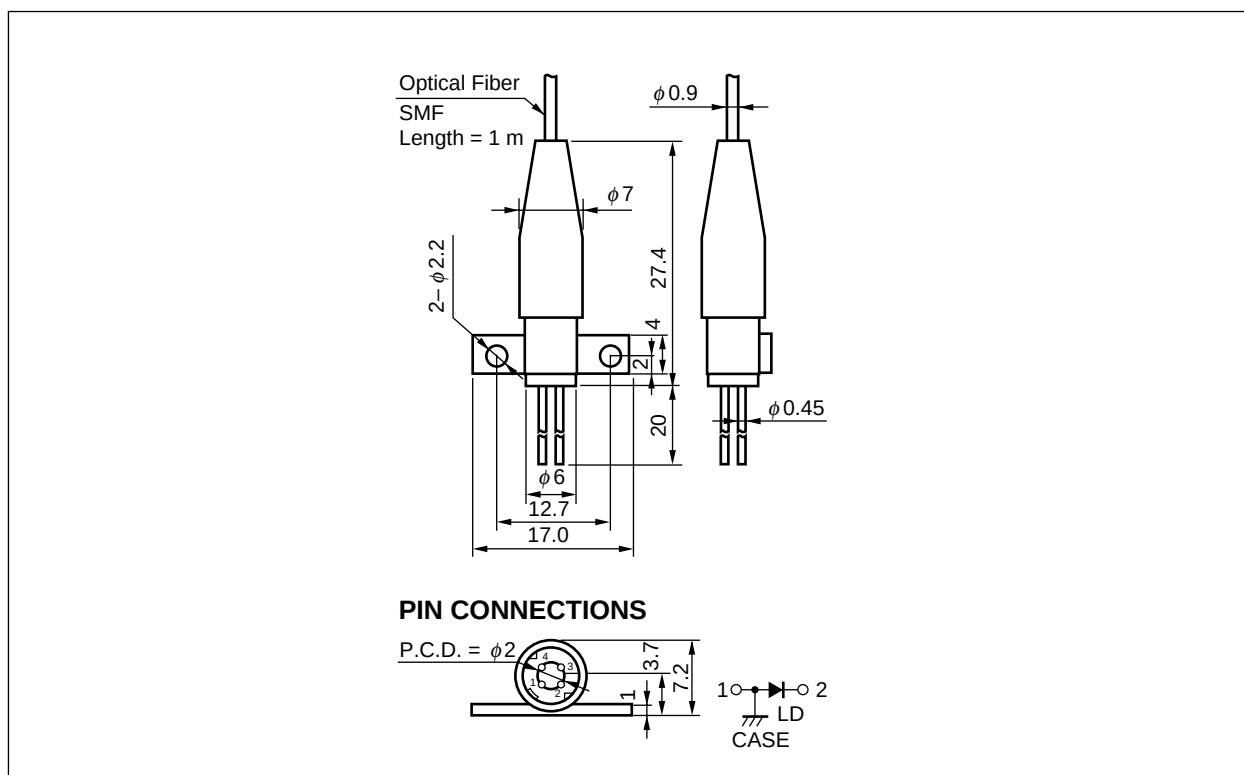
The NX7327BF-AA is a 1 310 nm Multiple Quantum Well (MQW) structured Fabry-Perot (FP) laser diode coaxial module with single mode fiber. This module is specified to operate under pulsed condition and designed for light source of Optical Time Domain Reflectometer (OTDR).

FEATURES

- High output power $P_r = 180 \text{ mW} @ I_{FP} = 1\,000 \text{ mA}^{*1}$
- Long wavelength $\lambda_c = 1\,310 \text{ nm}$

*1 Pulse Conditions: Pulse width (PW) = 10 μs , Duty = 1%

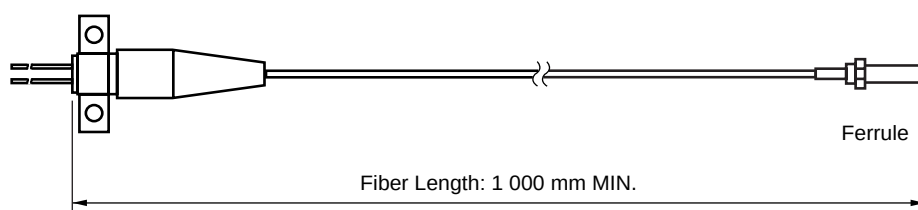
PACKAGE DIMENSIONS (UNIT: mm)



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OPTICAL FIBER CHARACTERISTICS

Parameter	Specification	Unit
Mode Field Diameter	9.3±0.5	μm
Cladding Diameter	125±2	μm
Maximum Cladding Noncircularity	2	%
Maximum Core/Cladding Concentricity	1.6	%
Outer Diameter	0.9±0.1	mm
Cut-off Wavelength	1 140 to 1 280	nm
Minimum Fiber Bending Radius	30	mm
Fiber Length	1 000 MIN.	mm



ORDERING INFORMATION

Part Number	Flange Type
NX7327BF-AA	flat mount flange

ABSOLUTE MAXIMUM RATINGS (T_c = 25°C, unless otherwise specified)

Parameter	Symbol	Ratings	Unit
Pulsed Forward Current*1	I _{FP}	1.2	A
Reverse Voltage	V _R	2.0	V
Operating Case Temperature	T _c	−20 to +60	°C
Storage Temperature	T _{stg}	−40 to +85	°C
Lead Soldering Temperature	T _{slid}	260 (10 sec)	°C
Relative Humidity (noncondensing)	RH	85	%

*1 Pulse Condition: Pulse Width (PW) = 10 μs, Duty = 1%

ELECTRO-OPTICAL CHARACTERISTICS (T_c = 25 °C)

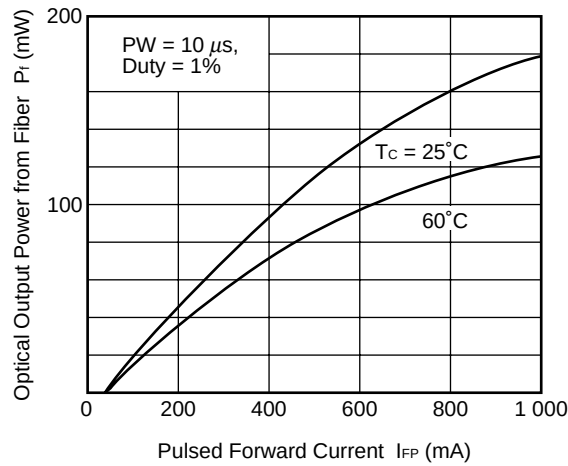
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Forward Voltage	V _{FP}	I _{FP} = 1 000 mA, PW = 10 μs, Duty = 1%		2.5	4.0	V
Threshold Current	I _{th}			35	65	mA
Optical Output Power from Fiber	P _f	I _{FP} = 1 000 mA, PW = 10 μs, Duty = 1%	110	180		mW
Center Wavelength	λ _c	RMS (−20 dB), I _{FP} = 1 000 mA, PW = 10 μs, Duty = 1%	1 290	1 310	1 330	nm
Spectral Width	σ	RMS (−20 dB), I _{FP} = 1 000 mA, PW = 10 μs, Duty = 1%		4.5	10.0	nm
Rise Time	t _r	10-90%			2.0	ns
Fall Time	t _f	90-10%			2.0	ns

ELECTRO-OPTICAL CHARACTERISTICS (T_c = 0 to +60°C)

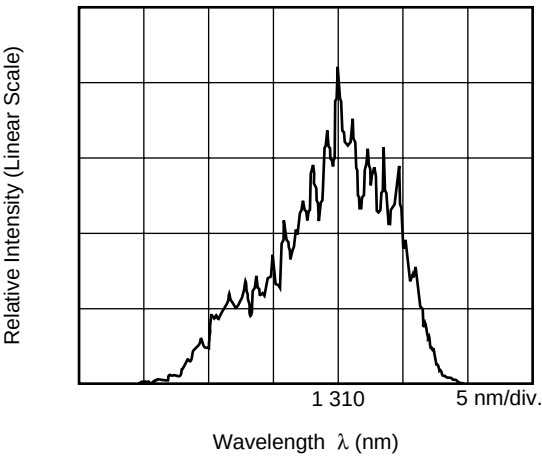
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Threshold Current	I _{th}				80	mA
Optical Output Power from Fiber	P _f	I _{FP} = 1000 mA, PW = 10 μs, Duty = 1%	75			mW
Center Wavelength	λ _c	RMS (−20 dB), I _{FP} = 1 000 mA, PW = 10 μs, Duty = 1 %	1 280		1 342.5	nm
Temperature Dependency of Center Wavelength	Δλ/ΔT			0.35		nm/°C
Spectral Width	σ	RMS (−20 dB), I _{FP} = 1 000 mA, PW = 10 μs, Duty = 1 %			10	nm

TYPICAL CHARACTERISTICS (T_c = 25°C, unless otherwise specified)

OPTICAL OUTPUT POWER FROM FIBER vs. PULSED FORWARD CURRENT



SPECTRUM



Remark The graphs indicate nominal characteristics.

OTDR LD FAMILY

Part Number	Electro-Optical Characteristics (T _c = 25°C)			Conditions			Application	Package
	λ_c (nm)	P _f (mW)		I _{FP} (mA)	PW (μ s)	Duty (%)		
	TYP.	MIN.	TYP.					
NX7327BF-AA	1 310	110	180	1 000	10	1	OTDR	4-pin coax. with SMF
NX7328BF-AA	1 310	70	110	400	10	1	OTDR	4-pin coax. with SMF
NX7329BB-AA	1 310	25	50	400	10	1	OTDR	4-pin coax. with SMF
NX7526BF-AA	1 550	95	145	1 000	10	1	OTDR	4-pin coax. with SMF
NX7527BF-AA	1 550	120	145	1 000	10	1	OTDR	4-pin coax. with SMF
NX7528BF-AA	1 550	60	80	400	10	1	OTDR	4-pin coax. with SMF
NX7529BB-AA	1 550	20	40	400	10	1	OTDR	4-pin coax. with SMF

REFERENCE

Document Name	Document No.
Optical semiconductor devices for fiberoptic communications Selection Guide	P12480E
Opto-Electronics Devices Pamphlet	P13623E
Opto-Electronics Devices (CD-ROM)	P12944X
NEC semiconductor device reliability/quality control system ^{*1}	C11159E
Quality grades on NEC semiconductor devices ^{*1}	C11531E
SEMICONDUCTOR SELECTION GUIDE –Products and Packages– ^{*1}	X13769E

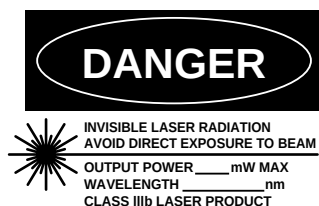
^{*1} Published by NEC Corporation

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SAFETY INFORMATION ON THIS PRODUCT



SEMICONDUCTOR LASER



AVOID EXPOSURE-Invisible
Laser Radiation is emitted from
this aperture

Warning Laser Beam	A laser beam is emitted from this diode during operation. The laser beam, visible or invisible, directly or indirectly, may cause injury to the eye or loss of eyesight. • Do not look directly into the laser beam. • Avoid exposure to the laser beam, any reflected or collimated beam.
Caution GaAs Products	The product contains gallium arsenide, GaAs. GaAs vapor and powder are hazardous to human health if inhaled or ingested. • Do not destroy or burn the product. • Do not cut or cleave off any part of the product. • Do not crush or chemically dissolve the product. • Do not put the product in the mouth. Follow related laws and ordinances for disposal. The product should be excluded from general industrial waste or household garbage.
Caution Optical Fiber	A glass-fiber is attached on the product. Handle with care. • When the fiber is broken or damaged, handle carefully to avoid injury from the damaged part or fragments.

►Business issue

NEC Compound Semiconductor Devices, Ltd.

5th Sales Group, Sales Division TEL: +81-3-3798-6372 FAX: +81-3-3798-6783 E-mail: salesinfo@csd-nec.com

NEC Compound Semiconductor Devices Hong Kong Limited

Hong Kong Head Office TEL: +852-3107-7303 FAX: +852-3107-7309
Taipei Branch Office TEL: +886-2-8712-0478 FAX: +886-2-2545-3859
Korea Branch Office TEL: +82-2-528-0301 FAX: +82-2-528-0302

NEC Electron Devices European Operations <http://www.nec.de/>

TEL: +49-211-6503-101 FAX: +49-211-6503-487

California Eastern Laboratories, Inc. <http://www.cel.com/>

TEL: +1-408-988-3500 FAX: +1-408-988-0279

►Technical issue

NEC Compound Semiconductor Devices, Ltd. <http://www.csd-nec.com/>

Sales Engineering Group, Sales Division
E-mail: techinfo@csd-nec.com FAX: +81-44-435-1918